NSN 5962-01-355-7293

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-355-7293

Body Length: 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 880.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Satellite communications terminal an/usc-3 (v) 1 **Features Provided:** Hermetically sealed and burn in and monolithic and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** 160.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 4.00 input picofarads and 8.00 output picofarads **Time Rating Per Chacteristic:** 45.00 nanoseconds access **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

20 printed circuit

Terminal Type And Quantity:

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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